

In re: Jeong-hee Chung et al.
Serial No.: To be assigned
Filed: Currently herewith
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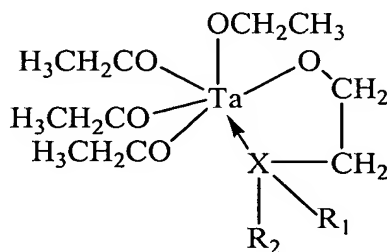
In the Specification:

Please replace the first paragraph under the heading "Cross-Reference to Related Application" on page 1 of the specification with the following amended paragraph:

~~The present application~~ This application is a divisional of US Application Serial No. 10/047,706 filed on January 15, 2002, which claims priority to Korean Patent Application No. 01-3165 filed January 19, 2001, the disclosures of which is are incorporated herein by reference in its entirety their entireties.

Please replace the Abstract on page 18 with the following amended paragraph:

Semiconductor capacitors comprise first electrodes, second electrodes, and tantalum oxide layers positioned between the first electrodes and the second electrodes. The tantalum oxide layers are formed by depositing at least one precursor and ozone gas, the at least one precursor represented by the formula:



wherein X is selected from the group consisting of nitrogen, sulfur, oxygen, and a carbonyl group; and wherein R₁ and R₂ are independently alkyl.